Supporting Information

Centimeter-Scale, Large-Area, Few-Layer 1T'-WTe₂ Films by Chemical Vapor Deposition and Its Long Term Stability in Ambient Condition

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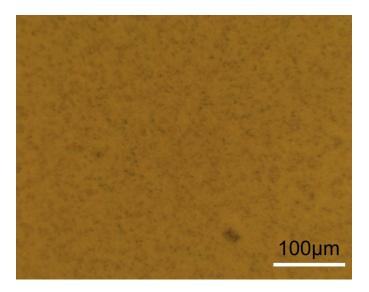


Figure S1 The optical image of produced WTe_2 film when the substrate is faced up.

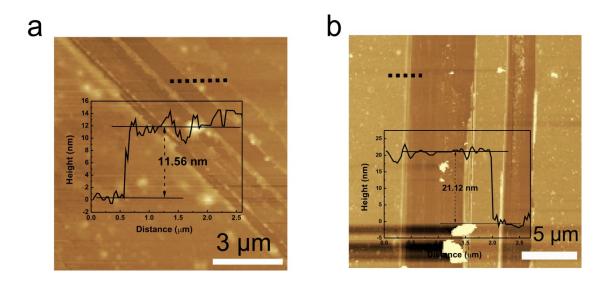


Figure S2 AFM image from related thicker few-layer WTe₂ samples. The thickness is around a) 11.56 nm, b) 21.12 nm. The thickness of as-grown WTe₂ from \sim 6 nm to \sim 20nm.

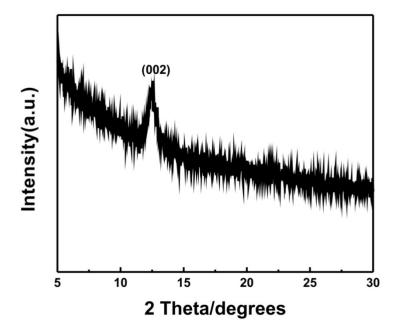


Figure S3 XRD pattern of few-layer WTe₂. The pattern shows one only diffraction peak at ~12.5° for 2 θ from the (002) plane, indicating a c-axis orientation.

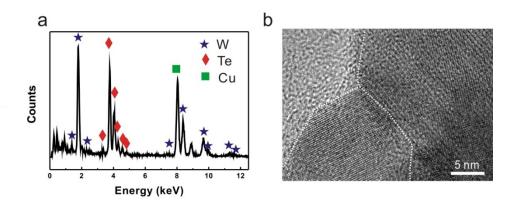


Figure S4 a) the energy-dispersive X-ray spectroscopy of prepared WTe₂. b) HTEM image of WTe₂, grain boundaries are plotted with white dash lines.

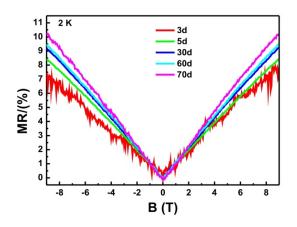


Figure S5 Exposure time dependent MRs for the relatively thicker WTe₂ sample

under 2K.